NSN 5962-01-249-0259

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View Online at https://aerobasegroup.com/nsn/5962-01-249-0259

Overall Width:

Between 0.800 inches and 1.160 inches

Body Length:

0.640 inches

Body Width:

Between 0.045 inches and 0.090 inches

Body Height:

Between 0.300 inches and 0.420 inches

Maximum Power Dissipation Rating:

1.02 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Electrostatic sensitive and bipolar and schottky and programmed and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Case Outline Source And Designator:

F-6 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

4.5 volts power source and 5.5 volts power source

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 flat leads

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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